NSN 5961-01-199-8947

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-199-8947 **Inclosure Material:** Plastic **Overall Length:** 0.520 inches **Overall Height:** 0.150 inches **Overall Width:** 0.410 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-202 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 drain to source voltage **Current Rating Per Characteristic:** 1.00 amperes drain current **Power Rating Per Characteristic:** 15.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0